

## HW17

20202041 Park, Nuri

### Scharfetter-Gummel

If  $|\phi_{i+1} - \phi_i| > 2V_T$ , one of coefficients for the electron densities becomes negative. We introduce Bernoulli function  $B(x) = \frac{x}{e^x - 1}$

$$B = -n_{i+1} \frac{1}{e^{\frac{\Delta\phi}{V_T}} - 1} + n_i \frac{e^{\Delta\phi/V_T}}{e^{\Delta\phi/V_T} - 1}$$

$$J_n = -\frac{qD_n}{\Delta x} \frac{\Delta\phi}{V_T} B$$

Implementing Bernoulli function, you should be careful where  $x=0$ ,  $\frac{x}{e^x - 1}$  have to be 1.

$|\phi_{i+1} - \phi_i| \simeq 0$ , original scheme is obtained.

$$\frac{J_{n,i+0.5}}{qD_n} \Delta x = n_{i+1} \left(1 - \frac{\phi_{i+1} - \phi_i}{2V_T}\right) - n_i \left(1 + \frac{\phi_{i+1} - \phi_i}{2V_T}\right)$$

$|\phi_{i+1} - \phi_i| \gg 0$ , by the Bernoulli function.

$$\begin{aligned} \frac{J_{n,i+0.5}}{qD_n} \Delta x &= -n_i \left( \frac{\phi_{i+1} - \phi_i}{V_T} \right) \\ J_{n,i+0.5} &= -q\mu_n n_i \left( \frac{\phi_{i+1} - \phi_i}{\Delta x} \right) \end{aligned}$$

### Poisson equation:

-Over the silicon layer

$$R_\phi = \frac{\epsilon_{i+1,j}\phi_{i+1,j} + \epsilon_{i-1,j}\phi_{i-1,j} + \epsilon_{i,j-1}\phi_{i,j-1} + \epsilon_{i,j+1}\phi_{i,j+1} - 4\epsilon_{i,j}\phi_{i,j}}{\epsilon_0} + \frac{\Delta x^2 q}{\epsilon_0} (N^+ - n_i) = 0$$

$$\frac{\partial R_\phi}{\partial \phi_{i\pm 1, j\pm 1}} = \frac{\epsilon_{i\pm 1, j\pm 1}}{\epsilon_0}, \quad \frac{\partial R_\phi}{\partial \phi_{i, j}} = -\frac{4\epsilon_{i, j}}{\epsilon_0}, \quad \frac{\partial R_\phi}{\partial n_i} = -\frac{\Delta x^2 q}{\epsilon_0}$$

- boundary example : left top

$$R_\phi = \frac{\epsilon_{0,1}\phi_{0,1} + \epsilon_{1,0}\phi_{1,0} - 2\epsilon_{0,0}\phi_{0,0}}{2\epsilon_0} = 0$$

$$\frac{\partial R_\phi}{\partial \phi_{0,1}} = \frac{\epsilon_{0,1}}{\epsilon_0}, \quad \frac{\partial R_\phi}{\partial \phi_{1,0}} = \frac{\epsilon_{1,0}}{\epsilon_0}, \quad \frac{\partial R_\phi}{\partial \phi_{0,0}} = -\frac{-\epsilon_{0,0}}{\epsilon_0}$$

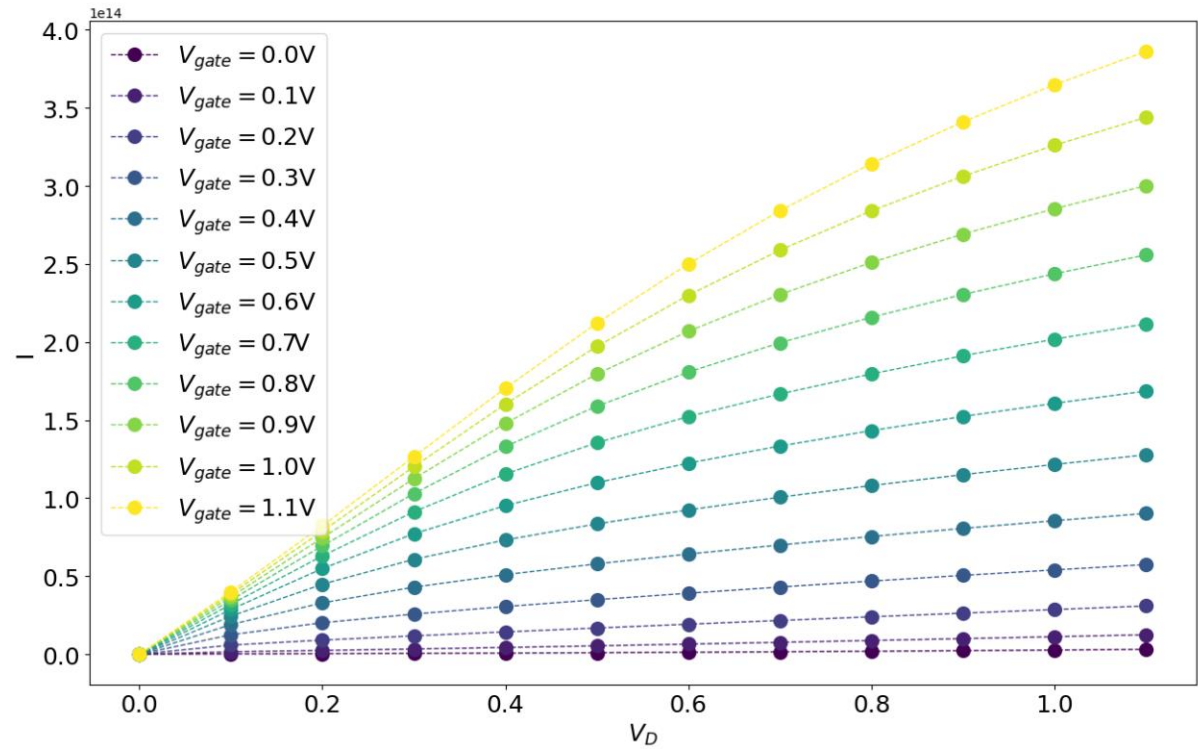


$$|\phi_{i+1} - \phi_i| \gg 0 :$$

$$\begin{aligned} & \frac{J_{n,i+0.5,j} + J_{n,i,j+0.5} - J_{n,i-0.5,j} - J_{n,i,j-0.5}}{qD_n} \Delta x \\ &= -n_{i,j} \left( \frac{\phi_{i+1,j} - \phi_{i,j}}{V_T} \right) + n_{i-1,j} \left( \frac{\phi_{i,j} - \phi_{i-1,j}}{V_T} \right) - n_{i,j} \left( \frac{\phi_{i,j+1} - \phi_{i,j}}{V_T} \right) + n_{i,j-1} \left( \frac{\phi_{i,j} - \phi_{i,j-1}}{V_T} \right) \\ & \frac{\partial R_n}{\partial n_{i,j}} = - \left( \frac{\phi_{i+1,j} + \phi_{i,j+1} - \phi_{i,j}}{V_T} \right) \frac{qD_n}{\Delta x}, \\ & \frac{\partial R_n}{\partial n_{i-1,j}} = \left( \frac{\phi_{i,j} - \phi_{i-1,j}}{V_T} \right) \frac{qD_n}{\Delta x}, \\ & \frac{\partial R_n}{\partial n_{i,j-1}} = \left( \frac{\phi_{i,j} - \phi_{i,j-1}}{V_T} \right) \frac{qD_n}{\Delta x} \end{aligned}$$

$$\begin{aligned} & \frac{\partial R_n}{\partial \phi_{i+1,j}} = - \left( \frac{n_{i,j}}{V_T} \right) \frac{qD_n}{\Delta x}, \\ & \frac{\partial R_n}{\partial \phi_{i-1,j}} = - \left( \frac{n_{i-1,j}}{V_T} \right) \frac{qD_n}{\Delta x}, \\ & \frac{\partial R_n}{\partial \phi_{i,j+1}} = - \left( \frac{n_{i,j}}{V_T} \right) \frac{qD_n}{\Delta x}, \\ & \frac{\partial R_n}{\partial \phi_{i,j-1}} = - \left( \frac{n_{i,j-1}}{V_T} \right) \frac{qD_n}{\Delta x}, \\ & \frac{\partial R_n}{\partial \phi_{i,j}} = \left( \frac{n_{i,j} + n_{i-1,j} + n_{i,j-1}}{V_T} \right) \frac{qD_n}{\Delta x}, \end{aligned}$$

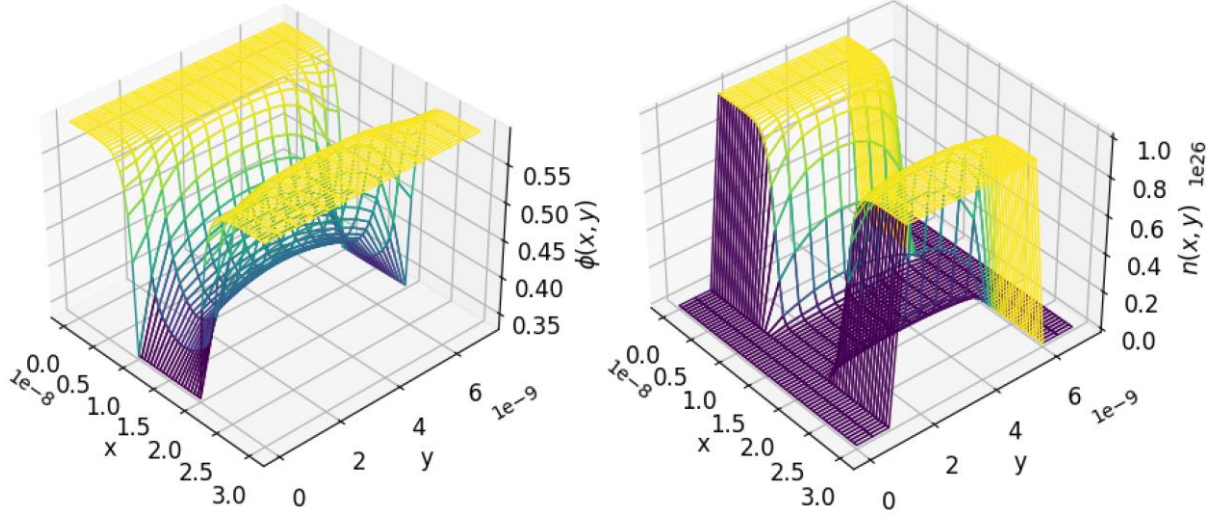
## Result



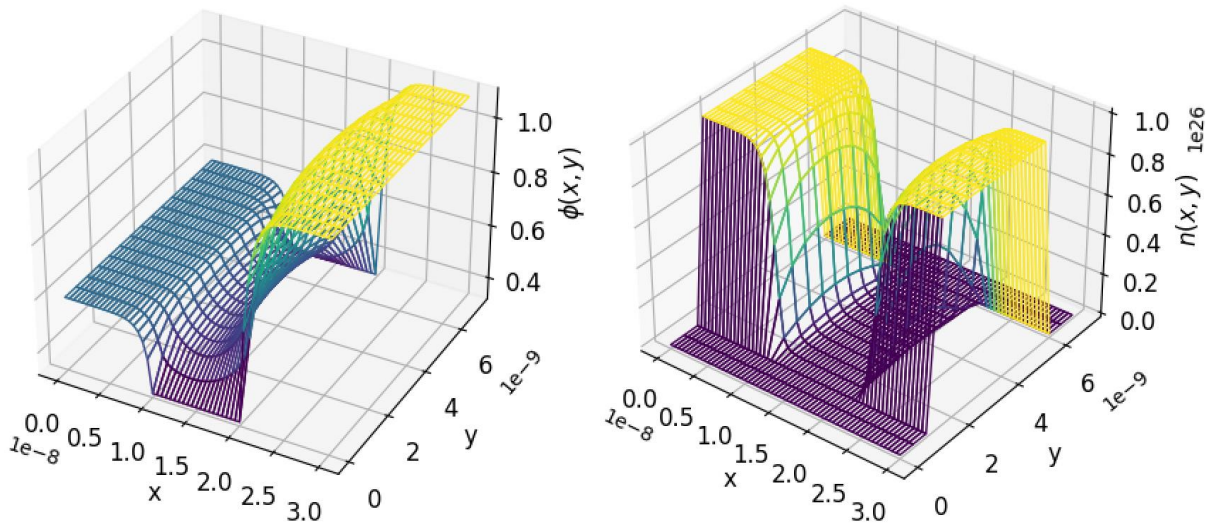
Higher the value of the  $V_{Gate}$  and  $V_{Drain}$ , higher the value of the terminal current.

### Detailed View

$-\phi(x,y)$  and  $n(x,y)$  with  $(V_{Gate}, V_{Drain}) = (0,0)$

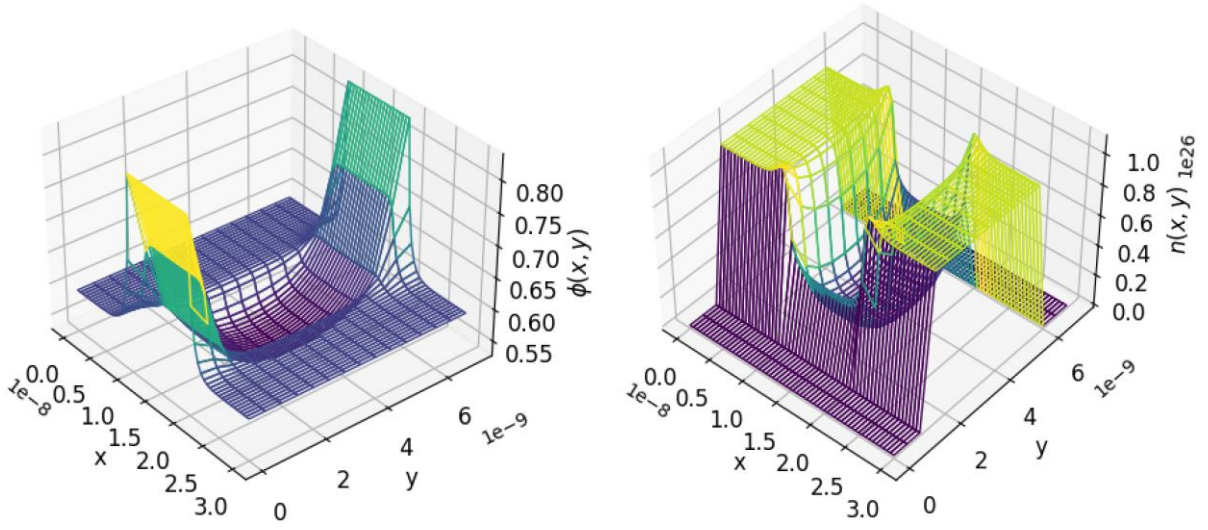


$-\phi(x,y)$  and  $n(x,y)$  with  $(V_{Gate}, V_{Drain}) = (0,0.5)$



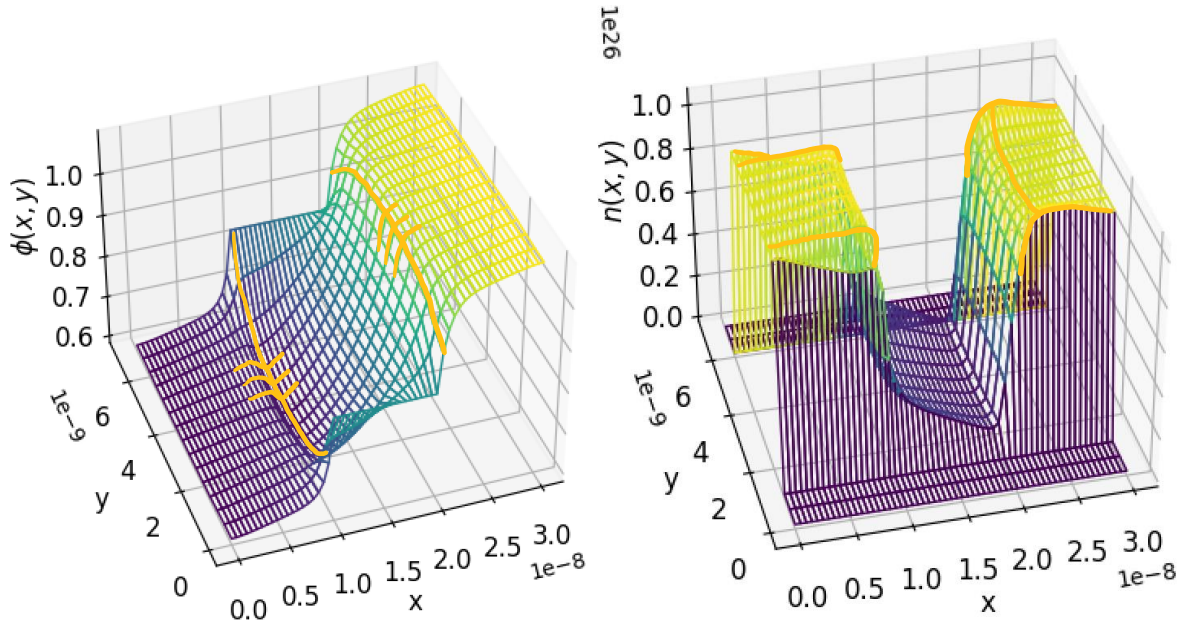
We find that drain voltage (0.5) makes  $\phi(x,y)$  unsymmetric. And  $n(x,y)$  is unchanged. This is because even though the absolute value of the  $\phi(x,y)$  is getting higher with  $V_{Drain}$ , the gradient of  $\phi(x,y)$  is similar. Thus, it could not affect the form of  $n(x,y)$ .

$-\phi(x,y)$  and  $n(x,y)$  with  $(V_{Gate}, V_{Drain}) = (0.5, 0)$



Now we give  $V_{Gate} = 0.5$ . Not only the  $\phi(x,y)$ ,  $n(x,y)$  also changed. Note that  $n(x,y)$  could exist where  $N_{acc} = 0$  which means  $x = (10nm : 20nm)$  in the silicon layer.

$-\phi(x,y)$  and  $n(x,y)$  with  $(V_{Gate}, V_{Drain}) = (0.5, 0.5)$



As we see above figures, the difference of the gradient of  $\phi(x,y)$  makes result of different form of  $n(x,y)$ .